## NSN 5961-01-185-4776

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-185-4776 **Inclosure Material:** Metal **Overall Length:** 0.165 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-4 **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.430 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 working peak reverse voltage **Current Rating Per Characteristic:** 20.00 amperes collector current, dc absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: A110a0